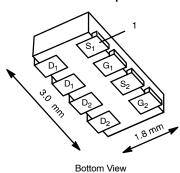
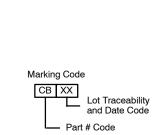


Dual N-Channel 2.5-V (G-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	r _{DS(on)} (Ω)	I _D (A)			
20	0.075 @ V _{GS} = 4.5 V	±4.2			
	0.134 @ V _{GS} = 2.5 V	±3.1			



1206-8 ChipFET™

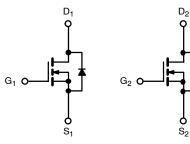




- TrenchFET® Power MOSFET
- 2.5-V Rated •
- Lead (Pb)-Free Version is RoHS Compliant



Available



N-Channel MOSFET

N-Channel MOSFET

Ordering Information: Si5904DC-T1 Si5904DC-T1—E3 (Lead (Pb)-Free)

		5 secs	Steady State	Unit
Drain-Source Voltage		20		V
Gate-Source Voltage		±12		
$T_A = 25^{\circ}C$	- I _D	±4.2	±3.1	
$T_A = 85^{\circ}C$		± 3.0	±2.2	
Pulsed Drain Current		±10		A
Continuous Source Current (Diode Conduction) ^a		1.8	0.9	
$T_A = 25^{\circ}C$	- P _D	2.1	1.1	w
$T_A = 85^{\circ}C$		1.1	0.6	
Operating Junction and Storage Temperature Range		-55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b, c}		260		
	$T_{A} = 85^{\circ}C$ $T_{A} = 25^{\circ}C$	$T_{A} = 85^{\circ}C$ I_{D} I_{DM} I_{S} $T_{A} = 25^{\circ}C$ P_{D}	$\begin{array}{c c} \hline T_{A} = 25^{\circ}C & & \pm 4.2 \\ \hline T_{A} = 85^{\circ}C & I_{D} & \pm 3.0 \\ \hline & & & & \\ \hline & & & & \\ \hline & & & & \\ \hline & & & &$	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$

THERMAL RESISTANCE RATINGS									
Parameter		Symbol	Typical	Maximum	Unit				
	$t \le 5 \text{ sec}$	R _{thJA}	50	60	°C/W				
Maximum Junction-to-Ambient ^a	Steady State		90	110					
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	30	40					

Notes

a.

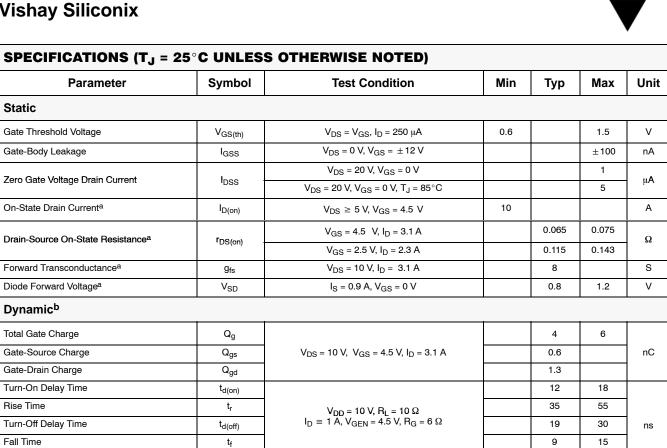
Surface Mounted on 1" x 1" FR4 Board. See Reliability Manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconb. nection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Si5904DC

Static

Vishay Siliconix



Notes

Pulse test; pulse width \leq 300 µs, duty cycle \leq 2%. a.

Source-Drain Reverse Recovery Time

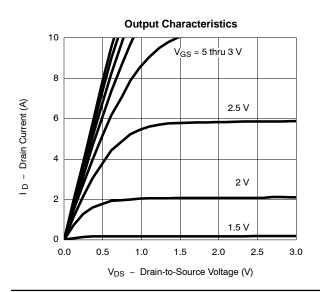
Guaranteed by design, not subject to production testing. b.

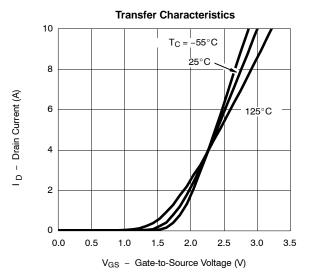
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

I_F = 0.9 A, di/dt = 100 A/μs

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

trr





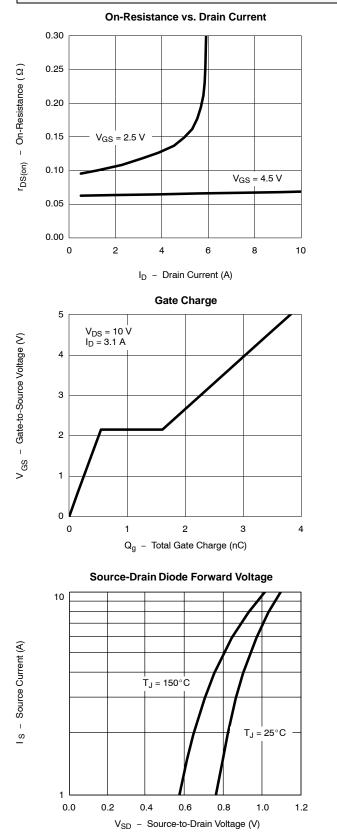
40

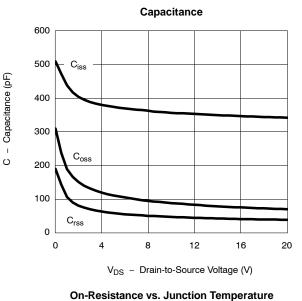
80

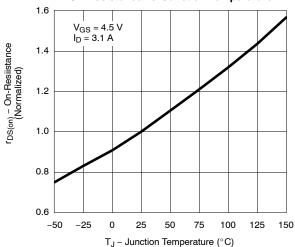


Si5904DC Vishay Siliconix

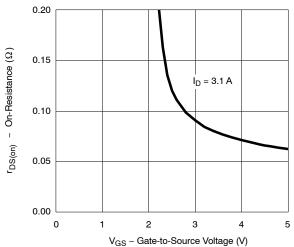
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)







On-Resistance vs. Gate-to-Source Voltage

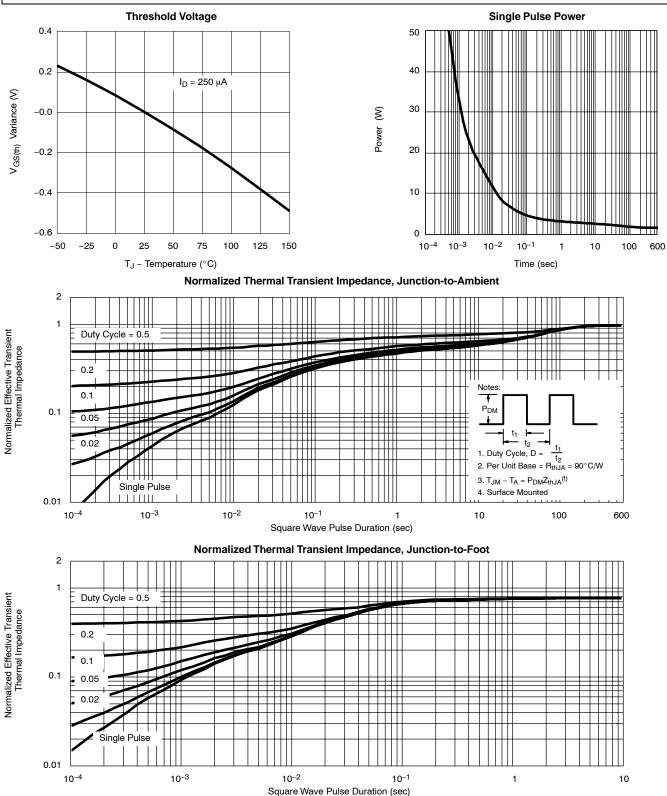


Si5904DC

Vishay Siliconix



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71065.

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Vishay

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